



30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

25 A

Features

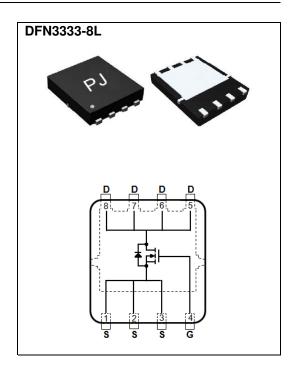
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@9A<18m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@4.5A$ < $28m\Omega$
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.001 ounces, 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	30	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _C =25°C	I _D	25	А	
	T _C =100°C		16		
Pulsed Drain Current(Note 1)	T _C =25°C	I _{DM}	100		
Power Dissipation	T _C =25°C	Po	21	W	
	T _C =100°C		8.4		
Continuous Drain Current	T _A =25°C	lο	8	Α	
	T _A =70°C		6.5		
Power Dissipation	T _A =25°C	0	2.0	144	
Power Dissipation	T _A =70°C	Pb	1.3	W	
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal resistance ^(Note 4,5)	Junction to Case	Rejc	5.95	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V,ID=250uA		-	-	V
Gate Threshold Voltage	$V_{\text{GS(th)}}$	V _{DS} =V _{GS} ,I _D =250uA	1.0	1.7	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =9A	-	16	18	mΩ
		V _{GS} =4.5V,I _D =4.5A	-	23	28	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	Igss	V _{GS=+} 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q_g	V _{DS} =15V, I _D =8A, V _{GS} =4.5V ^(Note 2,3)	-	4.3	-	nC
Gate-Source Charge	Q_{gs}		-	1.3	-	
Gate-Drain Charge	Q_{gd}		-	1.6	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	392	-	pF
Output Capacitance	Coss		-	76	-	
Reverse Transfer Capacitance	Crss		-	54	-	
Turn-On Delay Time	td _(on)	$\begin{array}{c} V_{\text{DS}=15V,\ I_{\text{D}}=1A,} \\ V_{\text{GS}=10V,\ R_{\text{G}}=6\Omega} \\ \text{(Note 2,3)} \end{array}$	-	5.9	-	ns
Turn-On Rise Time	tr		-	11	-	
Turn-Off Delay Time	td _(off)		-	17	-	
Turn-Off Fall Time	t _f		-	3.8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	,			-	25	А
Diode Forward Current	Is		-			
Diode Forward Voltage	V _{SD}	I _S =1A,V _{GS} =0V	-	0.73	1.0	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

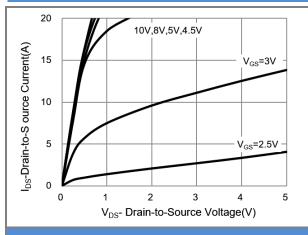


Fig.1 On-Region Characteristics

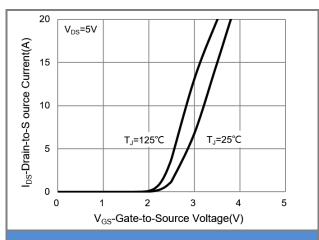


Fig.2 Transfer Characteristics

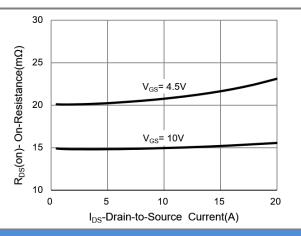


Fig.3 On-Resistance vs. Drain Current

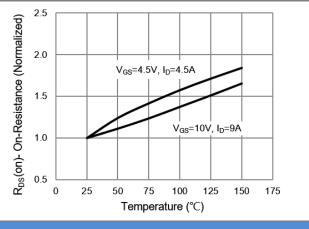


Fig.4 On-Resistance vs. Junction temperature

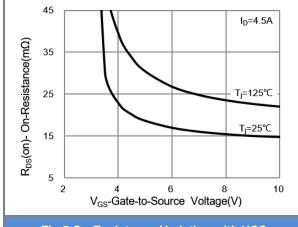


Fig.5 On-Resistance Variation with VGS.

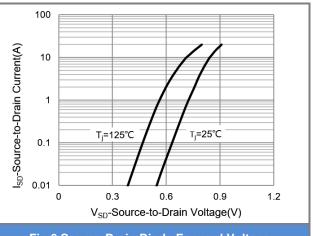


Fig.6 Source-Drain Diode Forward Voltage





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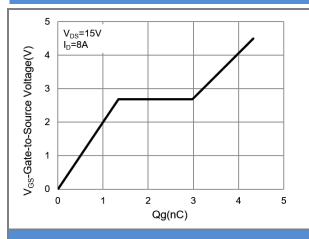


Fig.7 Gate-Charge Characteristics

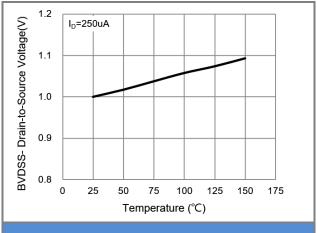


Fig.8 Breakdown Voltage Variation vs. Temperature.

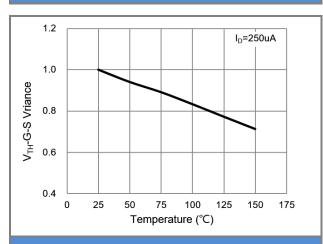


Fig.9 Threshold Voltage Variation with Temperature

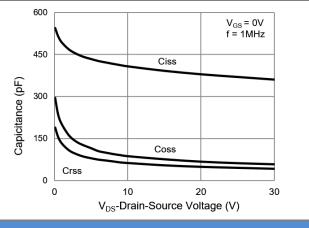
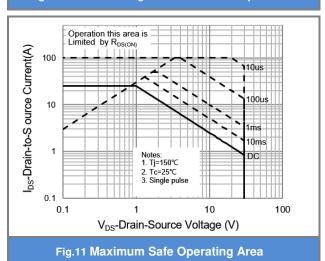


Fig.10 Capacitance vs. Drain-Source Voltage.







TYPICAL CHARACTERISTIC CURVES

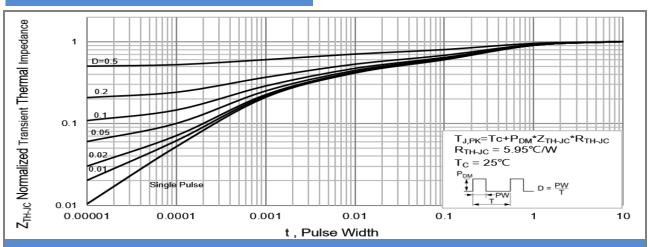


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

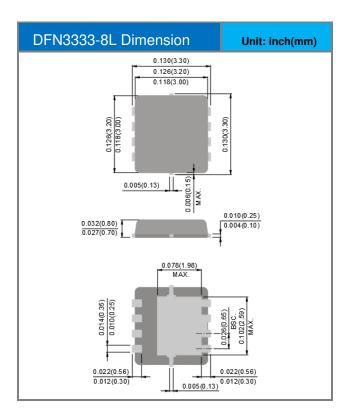


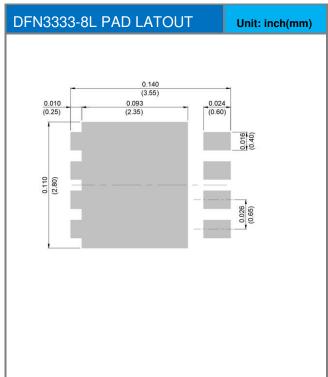


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4414P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4414	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout









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